



Sheet 1 of 1

FORM PTO-1449

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LIST OF REFERENCES CITED BY APPLICANT

(Use several sheets if necessary)

APPLICANT

S. TOMIOKA

FILING DATE

April 26, 2001

GROUP

~~1762~~ 1732

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NO.	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
	AA						
	AE						
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FOREIGN PATENT DOCUMENTS

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION YES NO PART.		
MOV	AA	10-256662	09/10/98	JAPAN				X	
	AB								
	AC								

TC 1700

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

MOV	AD	Nakamura, Shuji, "High-Power Ga P-N Junction Blue Light Emitting Diodes" 12/91 Japanese Journal Vol. 30, No.12A pp.L 1998-L 2001
MOV	AE	Polian, Grimsditch, and Grezegory, "Elastic Constraints of gallium nitride" 04/15/96, J.App.Phys., Vol.79, No.6
MOV	AF	G.H. Olsen and M. Ettenburg, "Calculated stresses in multilayered heteroepitaxial structures" 06/77, Journal of Applied Physics, Vol.48, No.6
MOV	AG	Hiramatsu, Detchprohm, and Akasaski, "Relaxation Mechanism of Thermal Stresses in the Heterostructure of GaN Grown on Sapphire by Vapor Phase Epitaxy" 04/93, J. Appl. Phys. Vol.23 Part 1, No.4 pp.1528-1533
MOV	AH	Bernstein, "Elastic Constants of Synthetic Sapphire at 270C" 01/63, Journal of Applied Physics Vol.34, No. 1 pp.169-172
	AI	

EXAMINER

M. Vargast

DATE CONSIDERED

9/20/03

*EXAMINER:

Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.